

MECHANICAL DATA Dimensions in mm (inches)

0.89 (0.035)3.70 (0.146) 3.41 (0.134) 3.41 (0.134) 3.60 (0.142) Max 4.14 (0.163) 3.84 (0.151) 1 3 0.76 0.030 min. 16.02 (0.631) 15.73 (0.619) 10.69 (0.421) 10.39 (0.409) 2 9.67 (0.381) 0.50 (0.020) 0.26 (0.010) 9.38 (0.369) 11.58 (0.456) 11.28 (0.444)

SMD 1 PACKAGE (TO-276AB)

Pad 1 – Source

Pad 2 – Drain Pad 3 – Gate

N-CHANNEL POWER MOSFET

V _{DSS}	200V
I _{D(cont)}	27.4A
R _{DS(on)}	0.100Ω

FEATURES

- HERMETICALLY SEALED SURFACE MOUNT PACKAGE
- SMALL FOOTPRINT EFFICIENT USE OF PCB SPACE.
- SIMPLE DRIVE REQUIREMENTS
- LIGHTWEIGHT
- HIGH PACKING DENSITIES
- **Note:** IRF250SMD also available with pins 1 and 3 reversed.

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

V _{GS}	Gate – Source Voltage	±20V		
I _D	Continuous Drain Current $(V_{GS} = 0, T_{case} = 25^{\circ}C)$	27.4A		
I _D	Continuous Drain Current $(V_{GS} = 0, T_{case} = 100^{\circ}C)$	17A		
I _{DM}	Pulsed Drain Current ¹	110A		
P _D	Power Dissipation @ T _{case} = 25°C	150W		
	Linear Derating Factor	1.2W/°C		
E _{AS}	Single Pulse Avalanche Energy ²	500mJ		
dv/dt	Peak Diode Recovery ³	5.0V/ns		
T _J , T _{stq}	Operating and Storage Temperature Range	–55 to 150°C		
TL	Package Mounting Surface Temperature (for 5 sec)	300°C		
$R_{\theta JC}$	Thermal Resistance Junction to Case	0.83°C/W		

Notes 1) Pulse Test: Pulse Width \leq 300ms, $\delta \leq$ 2%

2) @ V_{DD} = 25V , L \geq 1.3mH , Peak I_L = 27.4A , Starting T_J = 25°C

3) @ $I_{SD} \leq 27.5 A$, di/dt $\leq 190 A/\mu s$, $V_{DD} \leq B V_{DSS}$, $T_J \leq 150^\circ C$

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IRFN250 2N7225U1



ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C unless otherwise stated)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
	STATIC ELECTRICAL RATINGS						4
BV _{DSS}	Drain – Source Breakdown Voltage	$V_{GS} = 0$	I _D = 1mA	200			V
ΔBV_{DSS}	Temperature Coefficient of	Reference to 25°C			0.00		11/00
ΔT_{J}	Breakdown Voltage	I _D = 1mA			0.29		V/°C
R _{DS(on)}	Static Drain – Source On–State Resistance ¹	V _{GS} = 10V	I _D = 17A			0.100	Ω
		V _{GS} = 10V	I _D = 27.4A			0.105	
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$	I _D = 250μA	2		4	V
9 _{fs}	Forward Transconductance ¹	$V_{DS} \ge 15V$	I _{DS} = 17A	9			2(Ω)
	Zero Gate Voltage Drain Current	V _{GS} = 0	$V_{DS} = 0.8 BV_{DSS}$			25	μΑ
IDSS			T _J = 125°C			250	
I _{GSS}	Forward Gate – Source Leakage	$V_{GS} = 20V$				100	n ^
I _{GSS}	Reverse Gate – Source Leakage	$V_{GS} = -20V$				-100	– nA
	DYNAMIC CHARACTERISTICS						-
C _{iss}	Input Capacitance	$V_{GS} = 0$			3500		pF
C _{oss}	Output Capacitance	V _{DS} = 25V	-		700		
C _{rss}	Reverse Transfer Capacitance	f = 1MHz			110		
	Tatal Cata Charge 1	V _{GS} = 10V	I _D = 22A	55		115	nC
Qg	Total Gate Charge ¹	$V_{DS} = 0.5 BV_{DSS}$	S	55		115	
Q _{gs}	Gate – Source Charge ¹	I _D = 22A		8		22	nC
Q _{gd}	Gate – Drain ("Miller") Charge ¹	$V_{DS} = 0.5 BV_{DSS}$	S	30		60	
t _{d(on)}	Turn–On Delay Time	1/(-100)/(-10)	= 100V V _{GS} = 10V -7.4A 2.35Ω			35	ns
t _r	Rise Time					190	
t _{d(off)}	Turn–Off Delay Time	$I_{\rm D} = 27.4$ A				170	
t _f	Fall Time	$R_{G} = 2.3522$				130	
	SOURCE – DRAIN DIODE CHARAC	TERISTICS					-
I _S	Continuous Source Current					27.4	
I _{SM}	Pulse Source Current ²					110	A
	Diada Earward Valtaga	I _S = 27.4A	T _J = 25°C			1.9	V
	Diode Forward Voltage	$V_{GS} = 0$				1.9	
t _{rr}	Reverse Recovery Time	I _F = 27.4A	T _J = 25°C			950	ns
Q _{rr}	Reverse Recovery Charge	d _i / d _t ≤ 100A/µs	s V _{DD} ≤ 30V			9.0	μC
t _{on}	Forward Turn-On Time			Negligible			1

Notes

1) Pulse Test: Pulse Width \leq 300ms, $\delta \leq$ 2%

2) Repetitive Rating - Pulse width limited by maximum junction temperature.

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